

3-TERMINAL NEGATIVE VOLTAGE REGULATOR

■ GENERAL DESCRIPTION

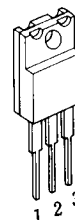
The NJM79M00 series of 3-Terminal Negative Voltage Regulators are constructed using the New JRC Planar epitaxial process. These regulators employ internal current limiting, thermal shutdown and safearea compensation, making them essentially indestructible. If adequate heat sinking is provided, they can deliver up to 500mA output current. They are intended as fixed voltage regulators in a wide range of applications including local (on-card) regulation for elimination of noise and distribution problems associated with single point regulation. In addition to use a fixed voltage regulators, these devices can be used with external components to obtain adjustable output voltages and currents.

■ FEATURES

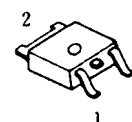
- Internal Short Circuit Current Limit
- Internal Thermal Overload Protection
- Excellent Ripple Rejection
- Guarantee'd 500mA Output Current
- Output Capacitor recommended electrolytic capacitor
- Package Outline TO-220F, TO-252
- Bipolar Technology

■ PACKAGE OUTLINE

(TO-220F)



(TO-252)



NJM79M00FA

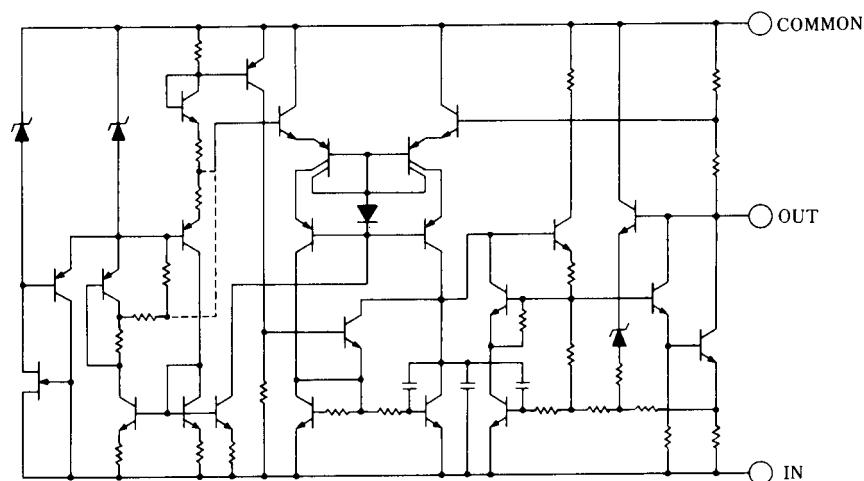
1. COMMON
2. IN
3. OUT

NJM79M00DL1A

1. COMMON
2. IN
3. OUT

(note) The radiation fin is connected to Pin 2.

■ EQUIVALENT CIRCUIT



NJM79M00

■ ABSOLUTE MAXIMUM RATINGS

(T_a=25°C)

PARAMETER	SYMBOL	MAXIMUM RATINGS		UNIT
Input Voltage	V _{IN}	79M05 to 79M09 79M12 to 79M15 79M18 to 79M24	-35 -35 -40	V
Storage Temperature Range	T _{stg}	TO-220F -40 to +150 TO-252 -40 to +150		°C
Operating Temperature Range		Operating Junction Temperature Operating Junction Temperature	T _j T _{opr} TO-220F -40 to +150 TO-252 -40 to +150 -40 to +85	°C
Power Dissipation	P _D	7.5(T _C ≤75°C)		W

■ THERMAL CHARACTERISTICS

			TO-220F	TO-252	°C/W
Thermal Resistance	Junction-to-Ambient Temperature	θ _{ja}	60	125	
	Junction-to-Case	θ _{jc}	7	12.5	

■ ELECTRICAL CHARACTERISTICS (T_J=25°C, C_{IN}=2.2μF, C_O=1.0μF)

Measurement is to be conducted in pulse testing

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
NJM79M05FA/DL1A						
Output Voltage	V _O	V _{IN} =-10V, I _O =0.35A	-4.8	-5.0	-5.2	V
Quiescent Current	I _Q	V _{IN} =-10V, I _O =0mA	-	2.2	5.0	mA
Load Regulation	ΔV _O - I _O	V _{IN} =-10V, I _O =0.005 to 0.5A	-	35	50	mV
Line Regulation	ΔV _O - V _{IN}	V _{IN} =-7 to -25V, I _O =0.35A	-	5	50	mV
Ripple Rejection	RR	V _{IN} =-10V, I _O =0.35A, e _{in} =2V _{P-P} , f=120Hz	50	58	-	dB
Output Noise Voltage	V _{NO}	V _{IN} =-10V, I _O =0.35A, BW=10Hz to 100kHz,	-	100	-	μV
Average Temperature Coefficient of Output Voltage	ΔV _O /ΔT	V _{IN} =-10V, I _O =5mA	-	-0.4	-	mV/°C

■ ELECTRICAL CHARACTERISTICS (T_J=25°C, C_{IN}=2.2μF, C_O=1.0μF)

Measurement is to be conducted in pulse testing.

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
NJM79M06FA/DL1A						
Output Voltage	V _O	V _{IN} =-11V, I _O =0.35A	-5.75	-6.0	-6.25	V
Quiescent Current	I _Q	V _{IN} =-11V, I _O =0mA	-	2.2	5.0	mA
Load Regulation	ΔV _O - I _O	V _{IN} =-11V, I _O =0.005 to 0.5A	-	35	60	mV
Line Regulation	ΔV _O - V _{IN}	V _{IN} =-8 to -25V, I _O =0.35A	-	5	60	mV
Ripple Rejection	RR	V _{IN} =-11V, I _O =0.35A, e _{in} =2V _{P-P} , f=120Hz	50	57	-	dB
Output Noise Voltage	V _{NO}	V _{IN} =-11V, I _O =0.35A, BW=10Hz to 100kHz,	-	110	-	μV
Average Temperature Coefficient of Output Voltage	ΔV _O /ΔT	V _{IN} =-11V, I _O =5mA	-	-0.5	-	mV/°C
NJM79M08FA/DL1A						
Output Voltage	V _O	V _{IN} =-14V, I _O =0.35A	-7.7	-8.0	-8.3	V
Quiescent Current	I _Q	V _{IN} =-14V, I _O =0mA	-	2.2	5.0	mA
Load Regulation	ΔV _O - I _O	V _{IN} =-14V, I _O =0.005 to 0.5A	-	40	80	mV
Line Regulation	ΔV _O - V _{IN}	V _{IN} =-10.5 to -25V, I _O =0.35A	-	8	80	mV
Ripple Rejection	RR	V _{IN} =-14V, I _O =0.35A, e _{in} =2V _{P-P} , f=120Hz	50	55	-	dB
Output Noise Voltage	V _{NO}	V _{IN} =-14V, I _O =0.35A, BW=10Hz to 100kHz,	-	130	-	μV
Average Temperature Coefficient of Output Voltage	ΔV _O /ΔT	V _{IN} =-14V, I _O =5mA	-	-0.7	-	mV/°C
NJM79M09FA/DL1A						
Output Voltage	V _O	V _{IN} =-15V, I _O =0.35A	-8.65	-9.0	-9.35	V
Quiescent Current	I _Q	V _{IN} =-15V, I _O =0mA	-	2.2	5.0	mA
Load Regulation	ΔV _O - I _O	V _{IN} =-15V, I _O =0.005 to 0.5A	-	40	90	mV
Line Regulation	ΔV _O - V _{IN}	V _{IN} =-11.5 to -25V, I _O =0.35A	-	8	80	mV
Ripple Rejection	RR	V _{IN} =-15V, I _O =0.35A, e _{in} =2V _{P-P} , f=120Hz	50	54	-	dB
Output Noise Voltage	V _{NO}	V _{IN} =-15V, I _O =0.35A, BW=10Hz to 100kHz,	-	150	-	μV
Average Temperature Coefficient of Output Voltage	ΔV _O /ΔT	V _{IN} =-15V, I _O =5mA	-	-0.8	-	mV/°C
NJM79M12FA/DL1A						
Output Voltage	V _O	V _{IN} =-19V, I _O =0.35A	-11.5	-12.0	-12.5	V
Quiescent Current	I _Q	V _{IN} =-19V, I _O =0mA	-	2.7	6.0	mA
Load Regulation	ΔV _O - I _O	V _{IN} =-19V, I _O =0.005 to 0.5A	-	30	120	mV
Line Regulation	ΔV _O - V _{IN}	V _{IN} =-14.5 to -30V, I _O =0.35A	-	3	80	mV
Ripple Rejection	RR	V _{IN} =-19V, I _O =0.35A, e _{in} =2V _{P-P} , f=120Hz	54	71	-	dB
Output Noise Voltage	V _{NO}	V _{IN} =-19V, I _O =0.35A, BW=10Hz to 100kHz,	-	150	-	μV
Average Temperature Coefficient of Output Voltage	ΔV _O /ΔT	V _{IN} =-19V, I _O =5mA	-	-0.4	-	mV/°C

NJM79M00

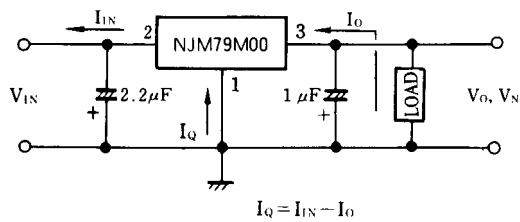
■ ELECTRICAL CHARACTERISTICS (T_J=25°C, C_{IN}=2.2μF, C_O=1.0μF)

Measurement is to be conducted in pulse testing.

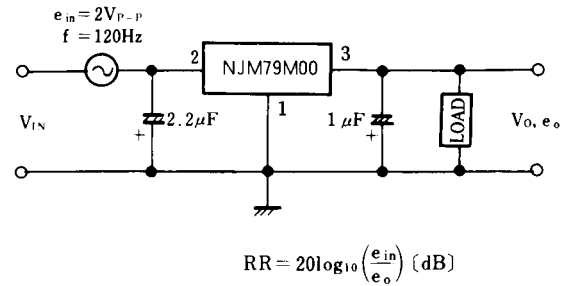
PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
NJM79M15FA/DL1A						
Output Voltage	V _O	V _{IN} =-23V, I _O =0.35A	-14.4	-15.0	-15.6	V
Quiescent Current	I _Q	V _{IN} =-23V, I _O =0mA	-	2.7	6.0	mA
Load Regulation	ΔV _O - I _O	V _{IN} =-23V, I _O =0.005 to 0.5A	-	30	150	mV
Line Regulation	ΔV _O - V _{IN}	V _{IN} =-17.5 to -30V, I _O =0.35A	-	3	80	mV
Ripple Rejection	RR	V _{IN} =-23V, I _O =0.35A, e _{IN} =2V _{P-P} , f=120Hz	54	70	-	dB
Output Noise Voltage	V _{NO}	V _{IN} =-23V, I _O =0.35A, BW=10Hz to 100kHz	-	170	-	μV
Average Temperature Coefficient of Output Voltage	ΔV _O /ΔT	V _{IN} =-23V, I _O =5mA	-	-0.5	-	mV/°C
NJM79M18FA/DL1A						
Output Voltage	V _O	V _{IN} =-27V, I _O =0.35A	-17.3	-18.0	-18.7	V
Quiescent Current	I _Q	V _{IN} =-27V, I _O =0mA	-	2.7	6.0	mA
Load Regulation	ΔV _O - I _O	V _{IN} =-27V, I _O =0.005 to 0.5A	-	35	180	mV
Line Regulation	ΔV _O - V _{IN}	V _{IN} =-21 to -33V, I _O =0.35A	-	4	80	mV
Ripple Rejection	RR	V _{IN} =-27V, I _O =0.35A, e _{IN} =2V _{P-P} , f=120Hz	54	69	-	dB
Output Noise Voltage	V _{NO}	V _{IN} =-27V, I _O =0.35A, BW=10Hz to 100kHz	-	200	-	μV
Average Temperature Coefficient of Output Voltage	ΔV _O /ΔT	V _{IN} =-27V, I _O =5mA	-	-0.6	-	mV/°C
NJM79M24FA/DL1A						
Output Voltage	V _O	V _{IN} =-33V, I _O =0.35A	-23.0	-24.0	-25.0	V
Quiescent Current	I _Q	V _{IN} =-33V, I _O =0mA	-	2.7	6.0	mA
Load Regulation	ΔV _O - I _O	V _{IN} =-33V, I _O =0.005 to 0.5A	-	40	240	mV
Line Regulation	ΔV _O - V _{IN}	V _{IN} =-27 to -38V, I _O =0.35A	-	5	80	mV
Ripple Rejection	RR	V _{IN} =-33V, I _O =0.35A, e _{IN} =2V _{P-P} , f=120Hz	54	66	-	dB
Output Noise Voltage	V _{NO}	V _{IN} =-33V, I _O =0.35A, BW=10Hz to 100kHz	-	300	-	μV
Average Temperature Coefficient of Output Voltage	ΔV _O /ΔT	V _{IN} =-33V, I _O =5mA	-	-0.8	-	mV/°C

■ TEST CIRCUIT

1. Output Voltage, Line Regulation, Load Regulation, Quiescent Current, Average Temperature Coefficient of Output Voltage, Output Noise Voltage



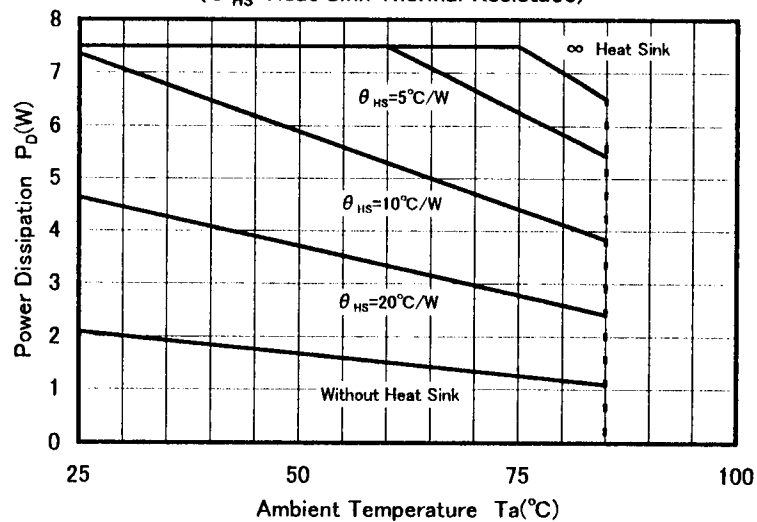
2. Ripple Rejection



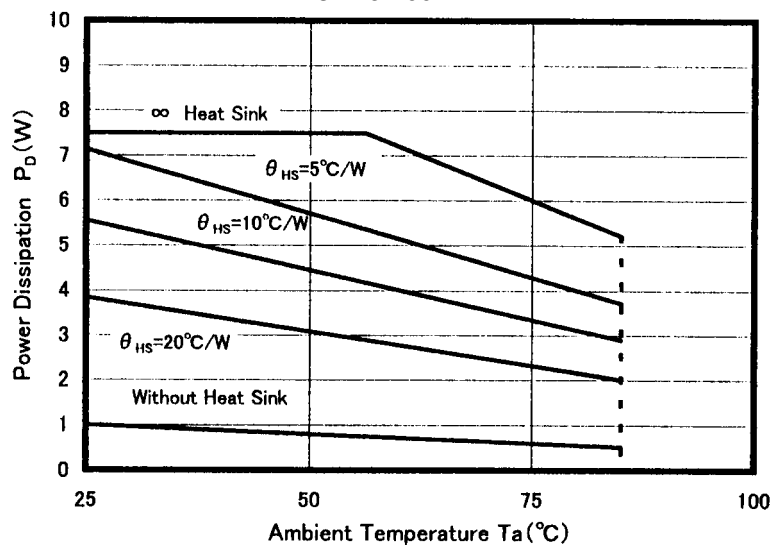
■ POWER DISSIPATION VS. AMBIENT TEMPERATURE

NJM79M00FA

(θ_{HS} = Heat Sink Thermal Resistace)



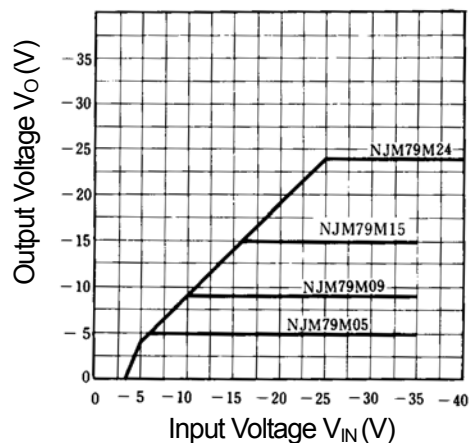
NJM79M00DL1A



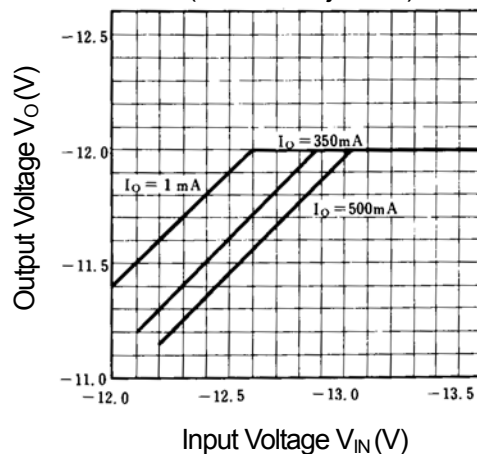
NJM79M00

■ TYPICAL CHARACTERISTICS

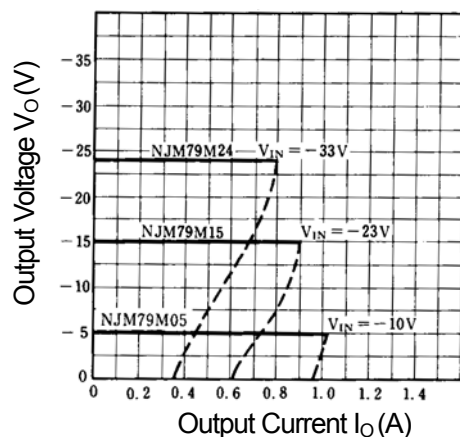
NJM79M00 Output Characteristics
($I_O = 0.35A$, $T_J = 25^\circ C$)



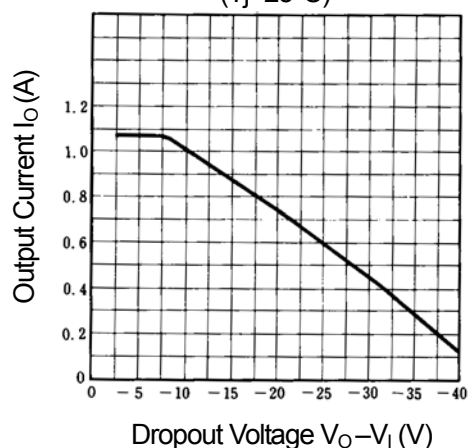
NJM79M12 Output Voltage vs. Low Input Voltage
($I_O = 0.35A$, $T_J = 25^\circ C$)



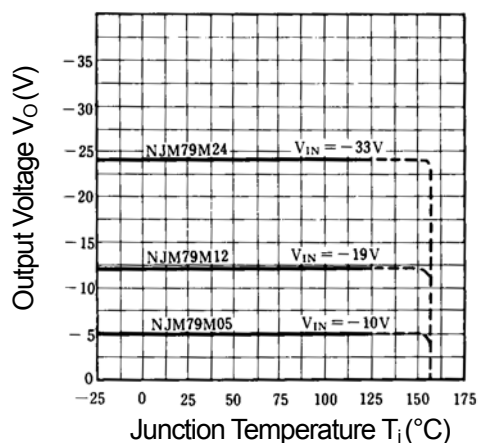
NJM79M05/15/24 Load Characteristics
($T_J = 25^\circ C$)



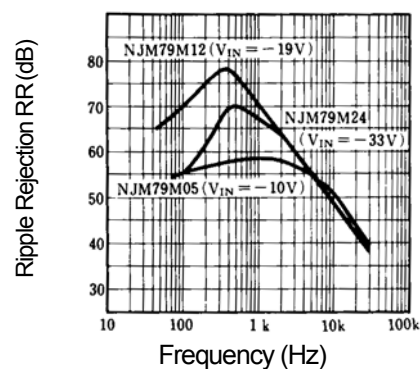
NJM79M00 Series Short Circuit Output Current
($T_J = 25^\circ C$)



NJM7805/15/24 Output Voltage vs. Junction Temperature

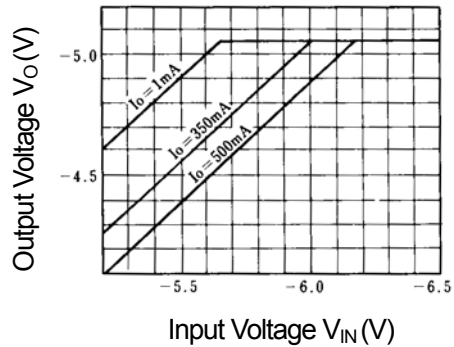


NJM79M05/15/24 Ripple Rejection vs. Frequency
($T_J = 25^\circ C$, $I_O = 0.35A$, $e_{in} = 2V_{P-P}$)

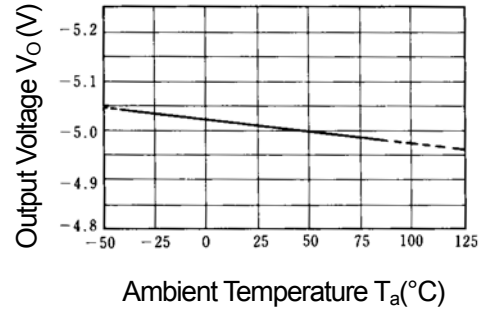


■ TYPICAL CHARACTERISTICS

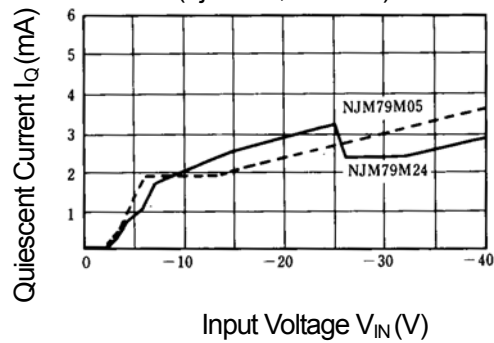
NJM79M05 Dropout Characteristics
($T_j=25^\circ\text{C}$)



NJM79M05 Output Voltage vs. Temperature



Quiescent Current vs. Input Voltage
($T_j=25^\circ\text{C}$, $I_O=0\text{mA}$)



[CAUTION]

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Наши преимущества:

- Оперативные поставки широкого спектра электронных компонентов отечественного и импортного производства напрямую от производителей и с крупнейших мировых складов;
- Поставка более 17-ти миллионов наименований электронных компонентов;
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- Лицензия ФСБ на осуществление работ с использованием сведений, составляющих государственную тайну;
- Поставка специализированных компонентов (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Aeroflex, Peregrine, Syfer, Eurofarad, Texas Instrument, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

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- Подбор оптимального решения, техническое обоснование при выборе компонента;
- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



Как с нами связаться

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